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520.37546X00

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

O I P E OCT 22 2001
P A T E N T S T R A D E M A R K O F F I C E
Applicants: TORII et al.
Serial No.: 09/391,250
Filed: September 7, 1999
For: SEMICONDUCTOR DEVICE AND ITS FABRICATION
METHOD
Group: 2811
Examiner: C. Nguyen

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AMENDMENT

Assistant Commissioner
for Patents
Washington, D.C. 20231

October 22, 2001

Sir:

In response to the Office Action dated June 20, 2001, the period of response for which extension is requested by the attached Petition for Extension of Time, please amend the above-identified application as follows:

In the Title:

Please amend the title to read:

"Memory Structure With A Ferroelectric Capacitor And
A Fabrication Method Thereof"